



### 20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 7.3 A

#### **Features**

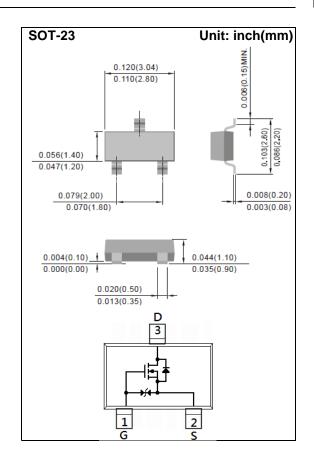
- $R_{DS(ON)}$ ,  $V_{GS}@4.5V$ ,  $I_{D}@5A<15.5m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @2.5V,  $I_{D}$ @4.5A<17.5m $\Omega$
- R<sub>DS(ON)</sub>, V<sub>GS</sub>@1.8V, I<sub>D</sub>@4A<22.5mΩ</li>
- Advanced Trench Process Technology
- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



# **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	20	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 10		
Continuous Drain Current (Note 4)		I <sub>D</sub>	7.3	A	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	29.2		
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 3,4)		$R_{ hetaJA}$	100	°C/W	





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	$BV_{DSS}$ $V_{GS}=0V$ ,	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	0.3	0.6	1	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =4.5V, $I_D$ =5A	-	13	15.5	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =4.5A	-	14.5	17.5	
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =4A	-	17	22.5	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V	-	-	1	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 10V, V <sub>DS</sub> =0V	-	-	<u>+</u> 10	uA
Dynamic (Note 5)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =10V, I <sub>D</sub> =9A, V <sub>GS</sub> =4.5V (Note 2,3)	-	16	-	nC
Gate-Source Charge	$Q_gs$		-	1.3	-	
Gate-Drain Charge	$Q_gd$		-	1.6	-	
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V, f=1MHZ	-	1177	-	pF
Output Capacitance	Coss		-	157	-	
Reverse Transfer Capacitance	Crss		-	134	-	
Turn-On Delay Time	td <sub>(on)</sub>	101/ 1	-	16	-	
Turn-On Rise Time	tr	$V_{DD}$ =10V, $I_{D}$ =1A, $V_{GS}$ =4.5V, $R_{G}$ =25 $\Omega$ (Note 2,3)	-	25	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	124	-	
Turn-Off Fall Time	tf	K <sub>G</sub> =2512	-	101	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is		-	-	1.5	Α
Diode Forward Current	.5					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A, V <sub>GS</sub> =0V	-	0.73	1	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 5. Guaranteed by design, not subject to production testing.





### **TYPICAL CHARACTERISTIC CURVES**

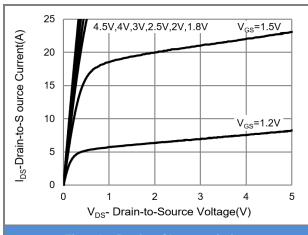
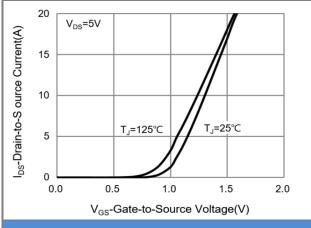


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

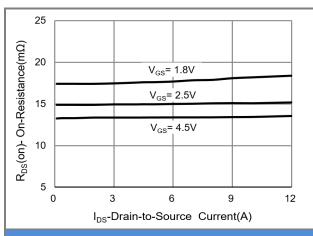


Fig.3 On-Resistance vs. Drain Current

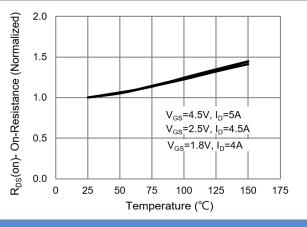


Fig.4 On-Resistance vs. Junction temperature

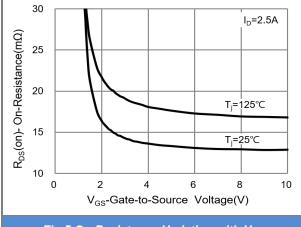
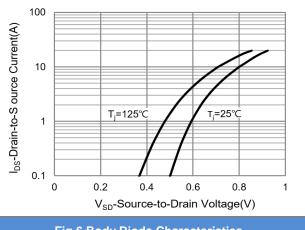


Fig.5 On-Resistance Variation with V<sub>GS</sub>



**Fig.6 Body Diode Characteristics** 





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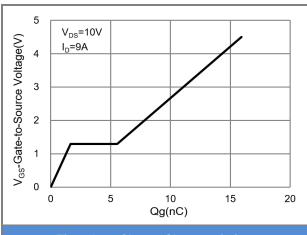


Fig.7 Gate-Charge Characteristics

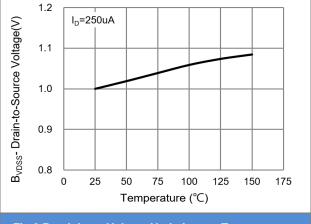


Fig.8 Breakdown Voltage Variation vs. Temperature

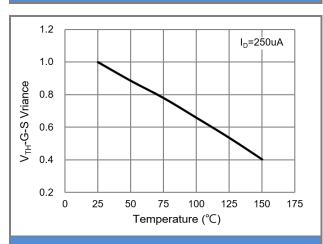


Fig.9 Threshold Voltage Variation with Temperature

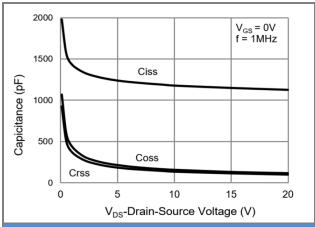


Fig.10 Capacitance vs. Drain-Source Voltage

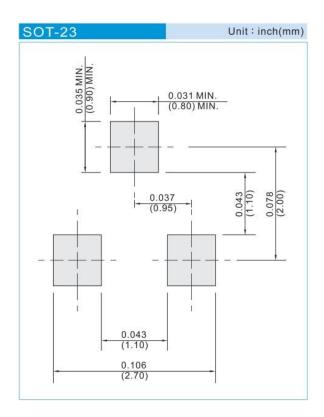




### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3456E_R1_00001	SOT-23	3K pcs / 7" reel	56E	Halogen free

### **Mounting Pad Layout**







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